

# DATA SHEET

## **BYW29E series** Rectifier diodes ultrafast, rugged

Product specification

August 2001



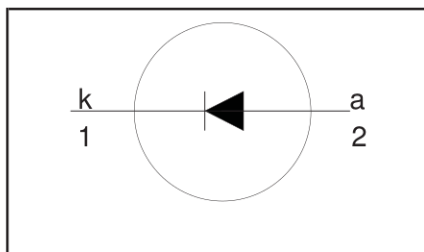
## Rectifier diodes ultrafast, rugged

## BYW29E series

### FEATURES

- Low forward volt drop
- Fast switching
- Soft recovery characteristic
- Reverse surge capability
- High thermal cycling performance
- Low thermal resistance

### SYMBOL



### QUICK REFERENCE DATA

$$V_R = 100V / 150V / 200V$$

$$V_F \leq 0.895V$$

$$I_{F(AV)} = 8A$$

$$I_{RRM} \leq 0.2A$$

$$t_{tr} \leq 25ns$$

### GENERAL DESCRIPTION

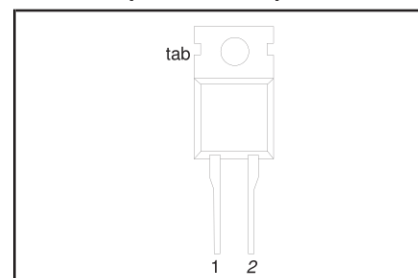
Ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYW29E series is supplied in the conventional leaded SOD59 (TO220AC) package.

### PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1   | cathode     |
| 2   | anode       |
| tab | cathode     |

### SOD59 (TO220AC)



### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

| SYMBOL      | PARAMETER                                 | CONDITIONS                                              | MIN. | MAX. |      |      | UNIT       |
|-------------|-------------------------------------------|---------------------------------------------------------|------|------|------|------|------------|
| $V_{RRM}$   | Peak repetitive reverse voltage           | BYW29E                                                  | -    | -100 | -150 | -200 | V          |
| $V_{RWM}$   | Working peak reverse voltage              |                                                         | -    | 100  | 150  | 200  | V          |
| $V_R$       | Continuous reverse voltage                |                                                         | -    | 100  | 150  | 200  | V          |
| $I_{F(AV)}$ | Average rectified forward current         | square wave; $\delta = 0.5$ ; $T_{mb} \leq 128^\circ C$ | -    | 8    |      |      | A          |
| $I_{FRM}$   | Repetitive peak forward current           | square wave; $\delta = 0.5$ ; $T_{mb} \leq 128^\circ C$ | -    | 16   |      |      | A          |
| $I_{FSM}$   | Non-repetitive peak forward current       | $t = 10ms$                                              | -    | 80   |      |      | A          |
|             |                                           | $t = 8.3ms$                                             | -    | 88   |      |      | A          |
|             |                                           | sinusoidal; with reapplied $V_{RRM(max)}$               | -    |      |      |      |            |
| $I_{RRM}$   | Peak repetitive reverse surge current     | $t_p = 2\mu s$ ; $\delta = 0.001$                       | -    | 0.2  |      |      | A          |
| $I_{RSM}$   | Peak non-repetitive reverse surge current | $t_p = 100\mu s$                                        | -    | 0.2  |      |      | A          |
| $T_j$       | Operating junction temperature            |                                                         | -    | 150  |      |      | $^\circ C$ |
| $T_{stg}$   | Storage temperature                       |                                                         | - 40 | 150  |      |      | $^\circ C$ |

### ESD LIMITING VALUE

| SYMBOL | PARAMETER                                 | CONDITIONS                                          | MIN. | MAX. | UNIT |
|--------|-------------------------------------------|-----------------------------------------------------|------|------|------|
| $V_C$  | Electrostatic discharge capacitor voltage | Human body model;<br>$C = 250pF$ ; $R = 1.5k\Omega$ | -    | 8    | kV   |

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### THERMAL RESISTANCES

| SYMBOL         | PARAMETER                                    | CONDITIONS  | MIN. | TYP. | MAX. | UNIT |
|----------------|----------------------------------------------|-------------|------|------|------|------|
| $R_{th\ j-mb}$ | Thermal resistance junction to mounting base | in free air | -    | -    | 2.7  | K/W  |
| $R_{th\ j-a}$  | Thermal resistance junction to ambient       |             | -    | 60   | -    | K/W  |

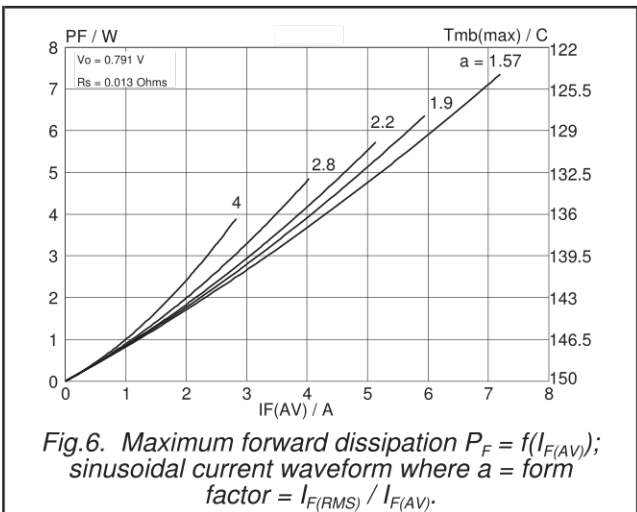
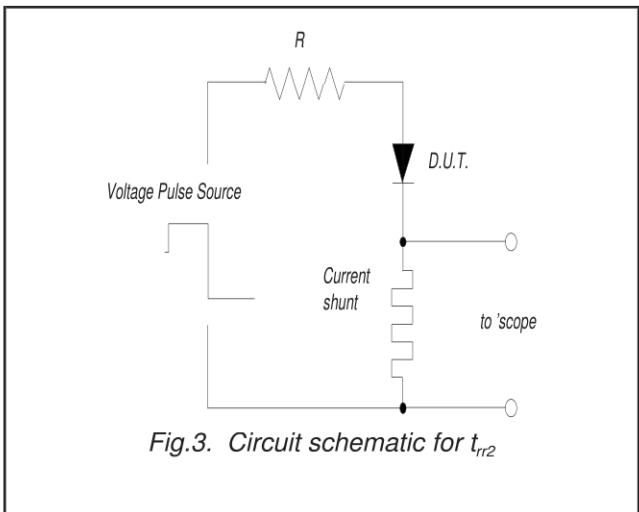
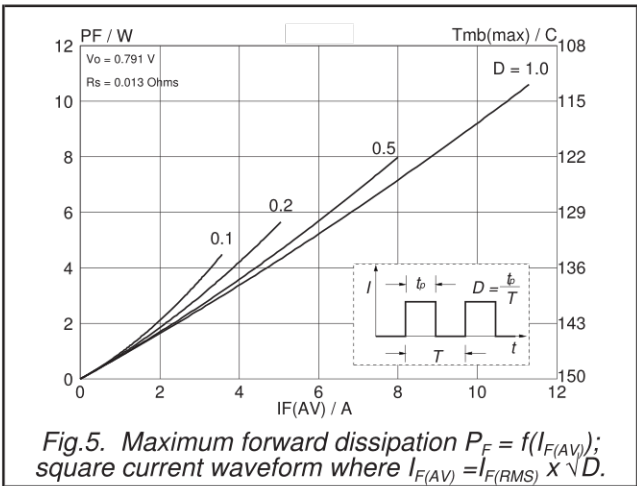
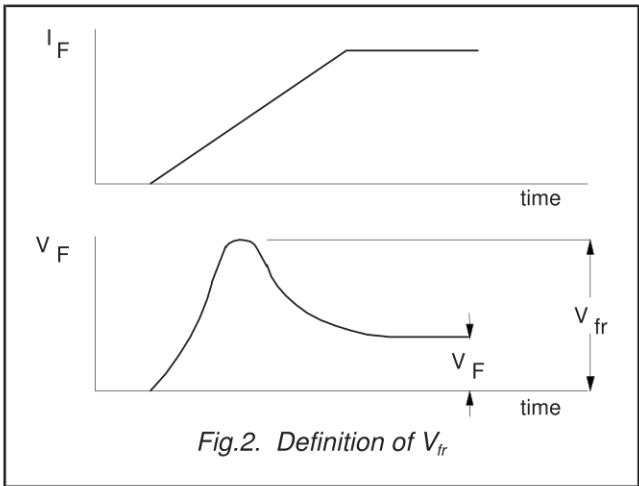
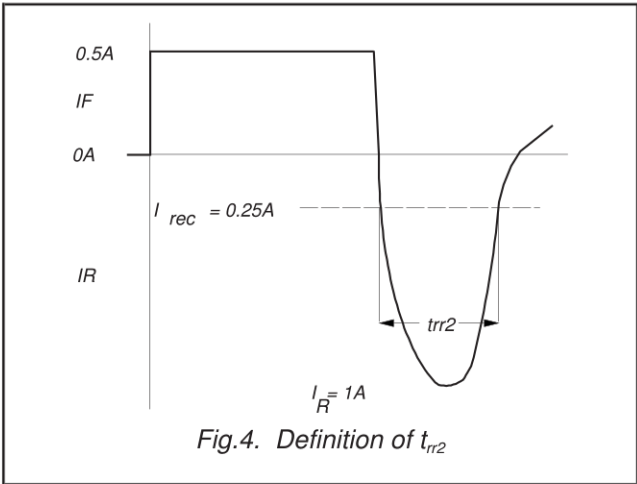
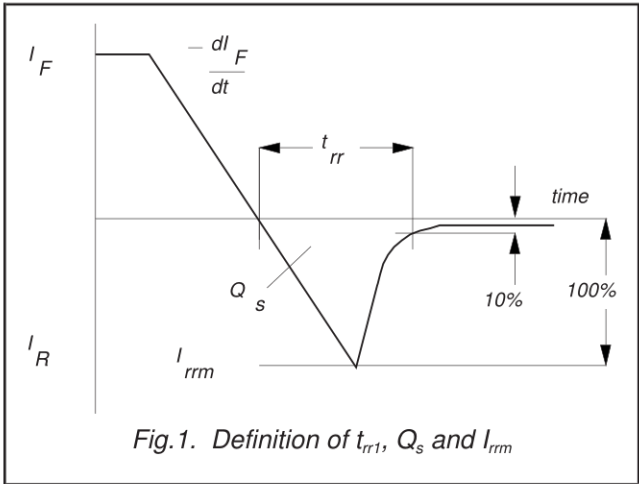
### ELECTRICAL CHARACTERISTICS

$T_j = 25\ ^\circ\text{C}$  unless otherwise specified

| SYMBOL    | PARAMETER                | CONDITIONS                                                                             | MIN. | TYP. | MAX.  | UNIT          |
|-----------|--------------------------|----------------------------------------------------------------------------------------|------|------|-------|---------------|
| $V_F$     | Forward voltage          | $I_F = 8\ \text{A}$ ; $T_j = 150\ ^\circ\text{C}$                                      | -    | 0.8  | 0.895 | V             |
|           |                          | $I_F = 8\ \text{A}$                                                                    | -    | 0.92 | 1.05  | V             |
|           |                          | $I_F = 20\ \text{A}$                                                                   | -    | 1.1  | 1.3   | V             |
| $I_R$     | Reverse current          | $V_R = V_{RWM}$                                                                        | -    | 2    | 10    | $\mu\text{A}$ |
|           |                          | $V_R = V_{RWM}$ ; $T_j = 100\ ^\circ\text{C}$                                          | -    | 0.2  | 0.6   | mA            |
| $Q_{rr}$  | Reverse recovered charge | $I_F = 2\ \text{A}$ ; $V_R \geq 30\ \text{V}$ ; $-di_F/dt = 20\ \text{A}/\mu\text{s}$  | -    | 4    | 11    | nC            |
| $t_{rr1}$ | Reverse recovery time    | $I_F = 1\ \text{A}$ ; $V_R \geq 30\ \text{V}$ ; $-di_F/dt = 100\ \text{A}/\mu\text{s}$ | -    | 20   | 25    | ns            |
| $t_{rr2}$ | Reverse recovery time    | $I_F = 0.5\ \text{A}$ to $I_R = 1\ \text{A}$ ; $I_{rec} = 0.25\ \text{A}$              | -    | 15   | 20    | ns            |
| $V_{fr}$  | Forward recovery voltage | $I_F = 1\ \text{A}$ ; $di_F/dt = 10\ \text{A}/\mu\text{s}$                             | -    | 1    | -     | V             |

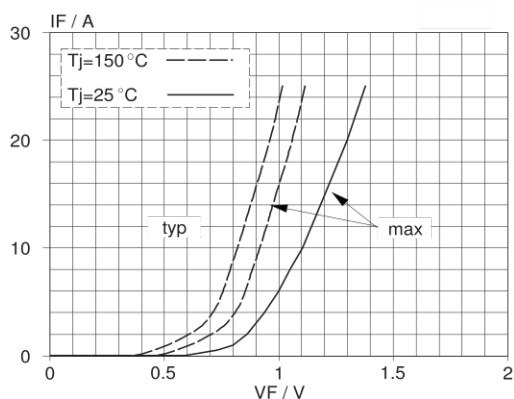
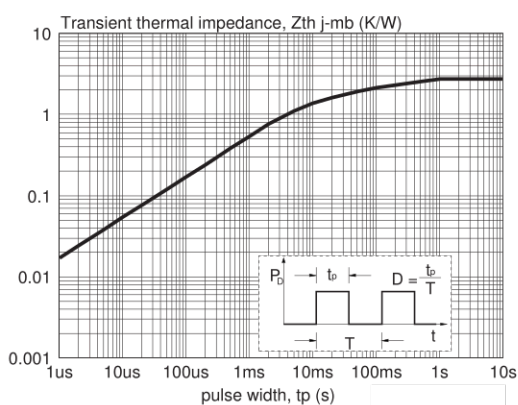
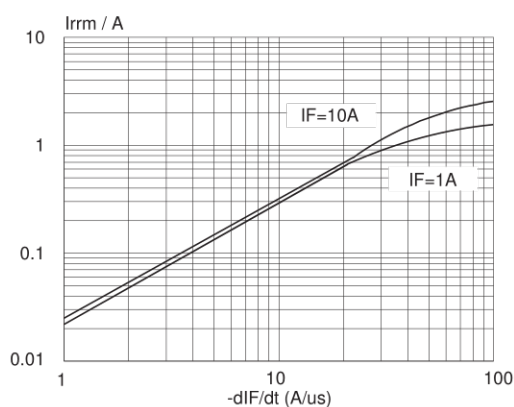
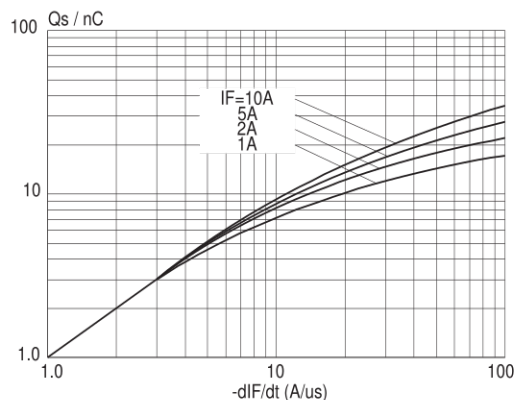
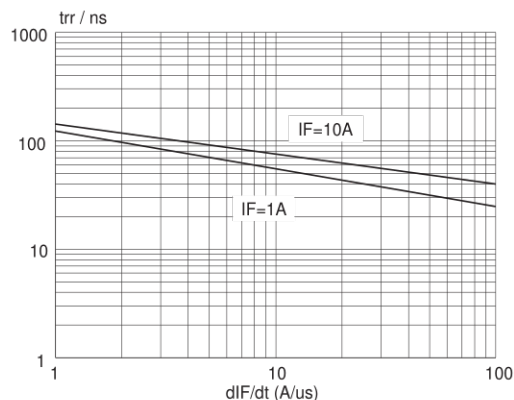
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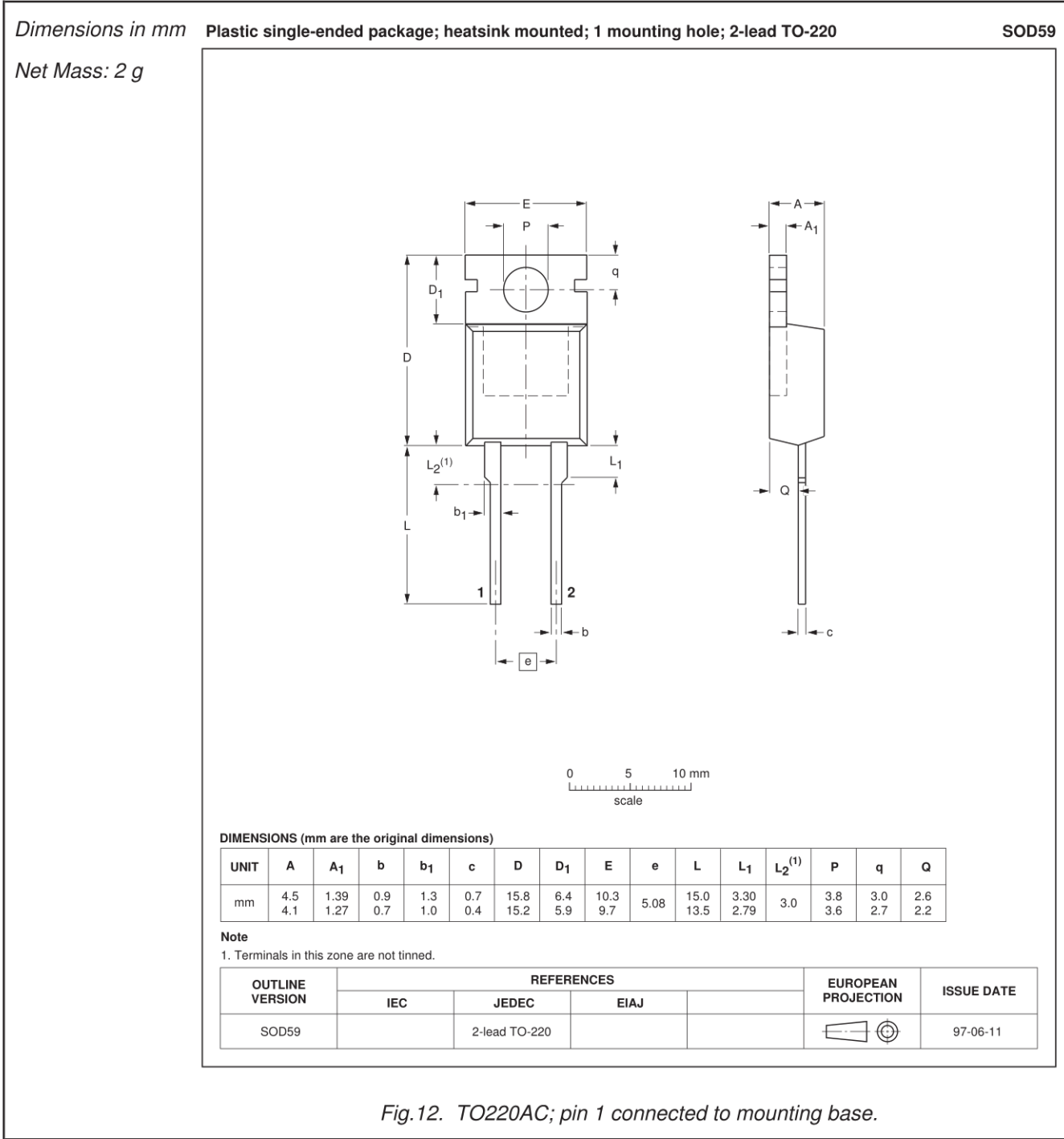


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MECHANICAL DATA



- Notes**
- 1. Refer to mounting instructions for TO220 envelopes.
  - 2. Epoxy meets UL94 V0 at 1/8".

## Legal information

### DATA SHEET STATUS

| DOCUMENT STATUS <sup>(1)</sup> | PRODUCT STATUS <sup>(2)</sup> | DEFINITION                                                                            |
|--------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
| Objective data sheet           | Development                   | This document contains data from the objective specification for product development. |
| Preliminary data sheet         | Qualification                 | This document contains data from the preliminary specification.                       |
| Product data sheet             | Production                    | This document contains the product specification.                                     |

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